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FAIRCHILD

November 2009

FDY4000CZ Complementary N & P-Channel PowerTrench[®] MOSFET

Features

Q1: N-Channel

- Max $r_{DS(on)} = 0.7\Omega$ at $V_{GS} = 4.5V$, $I_D = 600$ mA
- Max r_{DS(on)} = 0.85Ω at V_{GS} = 2.5V, I_D = 500mA
- Max r_{DS(on)} = 1.25Ω at V_{GS} = 1.8V, I_D =150 mA
- Q2: P-Channel
- Max r_{DS(on)} = 1.2Ω at V_{GS} = -4.5V, I_D = -350mA
- Max r_{DS(on)} = 1.6Ω at V_{GS} = -2.5V, I_D = -300mA
- Max r_{DS(on)} = 2.7Ω at V_{GS} = -1.8V, I_D = -150mA
- ESD protection diode (note 3)
- RoHS Compliant



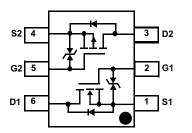
General Description

This Complementary N & P-Channel MOSFET has been designed using Fairchild Semiconductor's advanced Power Trench[®] process to optimize the $r_{DS(ON)}$ @ V_{GS} = 2.5V and specify the $r_{DS(ON)}$ @ V_{GS} = 1.8V.

Applications

- Level shifting
- Power Supply Converter Circuits
- Load/Power Switching Cell Phones, Pagers





MOSFET Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter		Q1	Q2	Units
V _{DS}	Drain to Source Voltage		20	-20	V
V _{GS}	Gate to Source Voltage		±12	±8	V
I _D Drain Current -Continuous (Note 1a) -Pulsed		600	-350		
			1000	-1000	mA
ſ	Power Dissipation (Steady State) (Note 1a)		625		mW
$P_{\rm D}$		Note 1b)	446		
T _J , T _{STG}	Operating and Storage Jaunting Temperature Range			o 150	°C
Therma	Characteristics				
$R_{ hetaJA}$	Thermal Resistance, Junction to Ambient (Note 1a) 200		00	°C/W	
$R_{ heta JA}$	Thermal Resistance, Junction to Ambient (Note 1b)			30	0/00

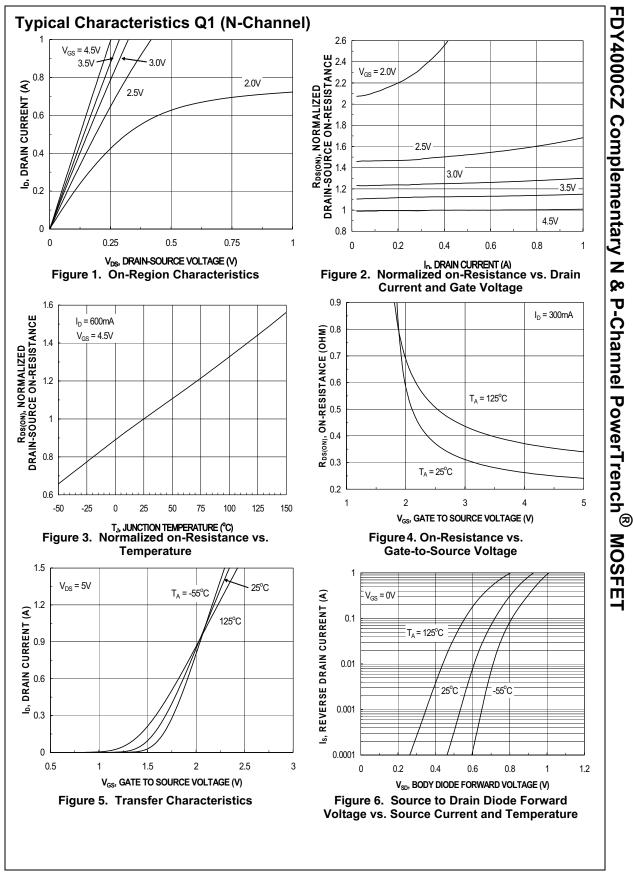
Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
E	FDY4000CZ	SC89-6	7"	8mm	3000units

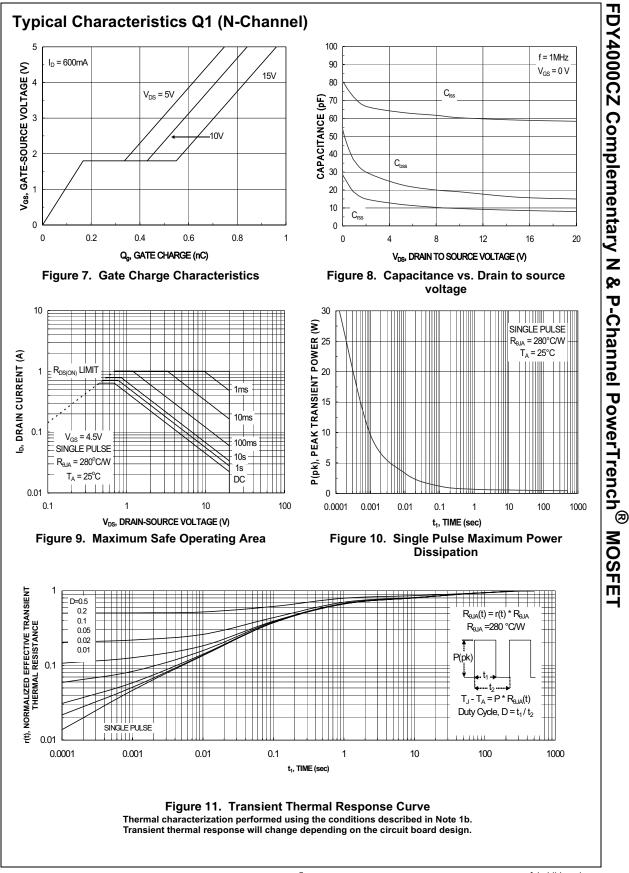
Symbol	Parameter	Test Conditions	Туре	Min	Тур	Мах	Units
Off Chara	cteristics						
B _{VDSS}	Drain to Source Breakdown Volt- age	$I_D = 250 \mu A, V_{GS} = 0V$ $I_D = -250 \mu A, V_{GS} = 0V$	Q1 Q2	20 -20			V
$\frac{\Delta B_{VDSS}}{\Delta T_{J}}$	Breakdown Voltage Temperature Coefficient	$I_D = 250\mu$ A, referenced to 25°C $I_D = -250\mu$ A, referenced to 25°C	Q1 Q2		15 -15		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 16V, V _{DS} =0V V _{DS} = -16V, V _{DS} =0V	Q1 Q2			1 -3	μA
I _{GSS}	Gate-Body Leakage	$V_{GS} = \pm 12V, V_{DS} = 0V$ $V_{GS} = \pm 4.5V, V_{DS} = 0V$ $V_{GS} = \pm 8V, V_{DS} = 0V$	Q1 Q1 Q2			±10 ±1 ±10	μA
On Chara	cteristics (note 2)						
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu A$ $V_{GS} = V_{DS}, I_D = -250 \mu A$	Q1 Q2	0.6 -0.6	1.0 -1.0	1.5 -1.5	V
$rac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250\mu A$, referenced to 25°C $I_D = -250\mu A$, referenced to 25°C	Q1 Q2		-3 3		mV/°C
	Drain to Source On Registence		Q1		0.30 0.40 0.80 0.35	0.70 0.85 1.25 1.00	0
r _{DS(on)}) Drain to Source On Resistance	$\label{eq:VGS} \begin{array}{l} V_{GS} = -4.5 \text{V}, \ I_D =350 \text{mA} \\ V_{GS} = -2.5 \text{V}, \ I_D = -300 \text{mA} \\ V_{GS} = -1.8 \text{V}, \ I_D = -150 \text{mA} \\ V_{GS} = -4.5 \text{V}, \ I_D = -350 \text{mA}, \ T_J = 125^\circ \text{C} \end{array}$	Q2		0.5 0.8 1.3 0.7	1.2 1.6 2.7 1.6	- Ω
9fs	Forward Transconductance	V _{DS} = 5V, I _D = 600mA V _{DS} = -5V, I _D = -350mA	Q1 Q2		1.8 1		S
Dynamic	Characteristics						
C _{iss}	Input Capacitance	Q1 V _{DS} = 10V, V _{GS} = 0V, f = 1MHz	Q1 Q2		60 100		pF
C _{oss}	Output Capacitance	Q2	Q1 Q2		20 30		pF
C _{rss}	Reverse Transfer Capacitance	V _{DS} = -10V, V _{GS} = 0V, f = 1MHz	Q1 Q2		10 15		pF
Switching	g Characteristics						
t _{d(on)}	Turn-On Delay Time	Q1 V _{DD} = 10V, I _D = 1A,	Q1 Q2		6 6	12 12	ns
t _r	Rise Time	V_{GS} = 4.5V, R_g = 6 Ω	Q1 Q2		8 13	16 23	ns
t _{d(off)}	Turn-Off Delay Time	Q2 V_{DD} = -10V, I_{D} = -0.5A,	Q1 Q2		8 8	16 16	ns
t _f	Fall Time	V_{GS} = -4.5V, R_g = 6 Ω	Q1 Q2		2.4 1	4.8 2	ns
Qg	Total Gate Charge	Q1 V _{DS} = 10V, I _D = 600mA, V _{GS} = 4.5V	Q1 Q2		0.8 1.0	1.1 1.4	nC
Q _{gs}	Gate to Source Gate Charge	Q2	Q1 Q2		0.16 0.2		nC
Q _{gd}	Gate to Drain "Miller"Charge	V_{DS} = -10V, I _D = -350mA, V _{GS} = -4.5V	Q1 Q2		0.26 0.3		nC

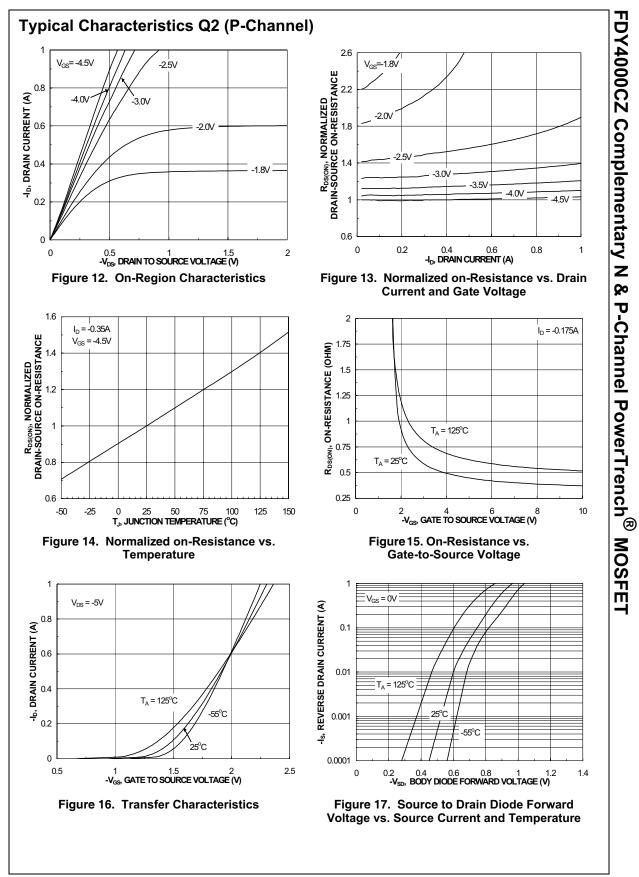
FDY4000CZ Complementary N & P-Channel PowerTrench[®] MOSFET

Symbol	Parameter	Test Conditions	Туре	Min	Тур	Max	Units
)rain-So	urce Diode Characteristics		_	_	_	_	
/ _{SD}	Source to Drain Diode Forward Voltage	V_{GS} = 0V, I _S = 150mA (Note 2) V_{GS} = 0V, I _S = -150mA (Note 2)	Q1 Q2		0.7 -0.8	1.2 -1.2	V
t _{rr}	Reverse Recovery Time	Q1 I _F = 600mA, di/dt = 100A/µs	Q1 Q2		8 11		ns
Q _{rr}	Reverse Recovery Charge	Q2 I _F = -350mA, di/dt = 100A/μs	Q1 Q2		1 2		nC
	a) 200°C/W w on a 1 in ² pad o occoco Scale 1:1 on letter size paper Pulse Width < 300us, Duty Cycle < 2.0%	hen mounted of 2 oz copper	or			n mounte d of 2 c	

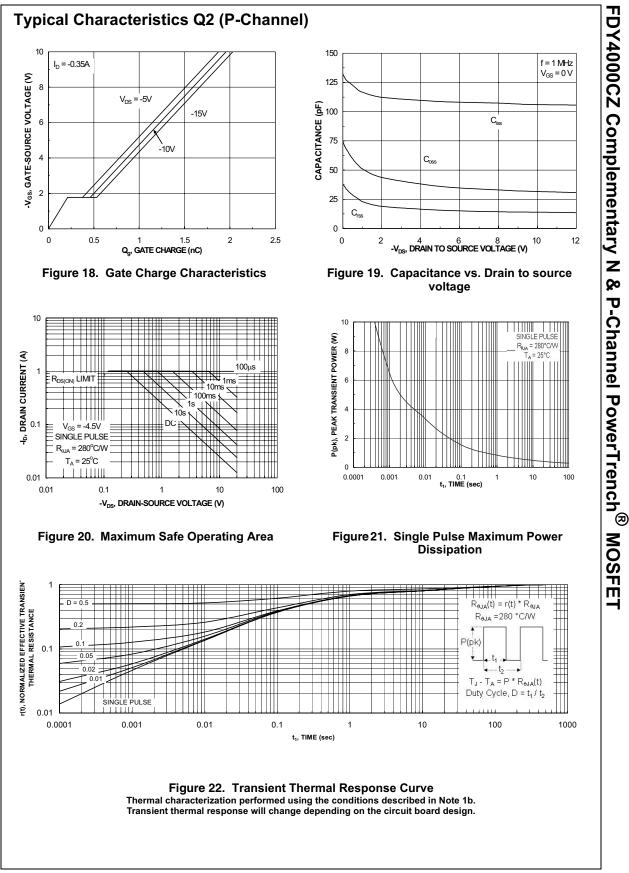


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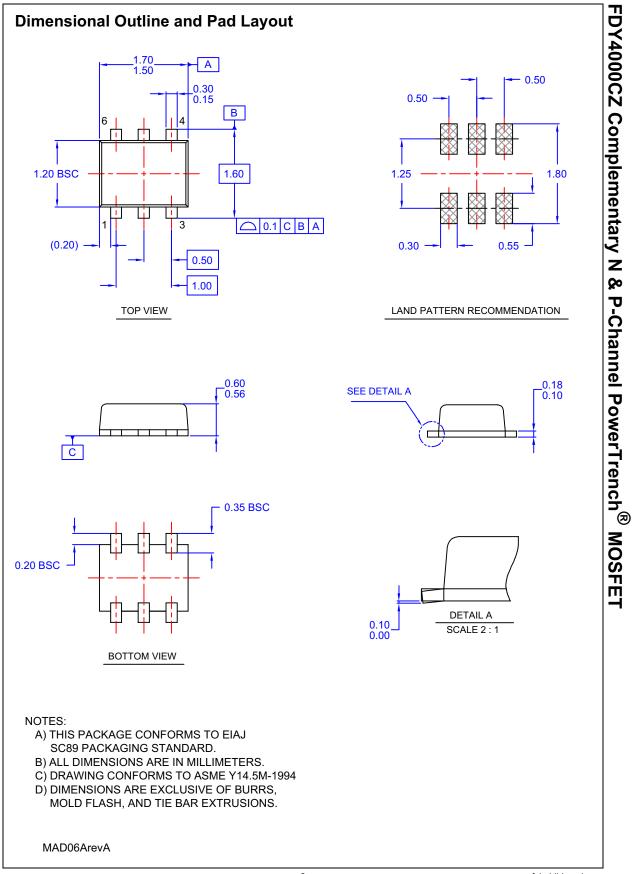




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